

BUL704

High voltage fast-switching NPN Power Transistor

General features

- NPN Transistor
- High voltage capability
- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed
- In compliance with the 2002/93/EC European Directive

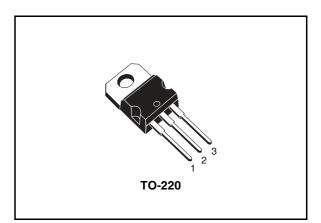
Description

The device is manufactured using high voltage Multi-Epitaxial Planar technology for high switching speeds and medium voltage capability.

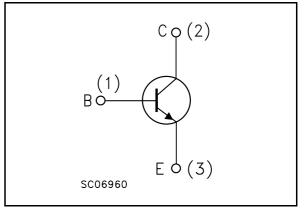
It uses a Cellular Emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.

Applications

- Electronic ballast for fluorescent lighting
- Dedicated for PFC solution in HF ballast halfbridge voltage fed



Internal schematic diagram



Order codes

Part Number	Marking	Package	Packing	
BUL704	BUL704	TO-220	Tube	

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Electrical ratings

Table 1. Absolute maximum	1 rating
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Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	700	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	400	V
V _{EBO}	Emitter-base voltage (I _C = 0)	10	V
۱ _C	Collector current	4	Α
I _{CM}	Collector peak current (t _P < 5ms)	8	Α
Ι _Β	Base current	2	Α
I _{BM}	Base peak current (t _P < 5ms)	4	Α
P _{tot}	Total dissipation at $T_c = 25^{\circ}C$	70	W
T _{stg}	Storage temperature	-65 to 150	°C
Т _Ј	Max. operating junction temperature	150	°C

Table 2. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction-case max	1.78	°C/W
R _{thj-amb}	Thermal resistance junction-amb max	62.5	°C/W

2 Electrical characteristics

($T_{case} = 25^{\circ}C$ unless otherwise specified)

	Parameter ctor cut-off current	Test Co	nditions	Min.	Тур.	Max.	Unit
	ctor cut-off current				. , թ.		Unit
		V _{CE} =700V				100	μA
(V _{BE}	=-1.5V)	V _{CE} =700V	Т _ј =125°С			500	μA
I _{CEO} Coller (I _B =0	ctor cut-off current))	V _{CE} =400V				250	μA
V_{EBO} Emitter (I _C =	er-base voltage 0)	I _E =10mA		10			V
V (D)	ctor-emitter ining voltage 0)	I _C =100mA	L =25mH	400			V
V _{CE(sat)} ⁽¹⁾ Colle	ctor-emitter	I _C =1A	I _B =0.2A			0.5	V
satura	ation voltage	I _C =2.5A	I _B =0.5A			0.8	V
V (1) Base	-emitter saturation	I _C =1A	I _B =0.2A			1.1	V
V _{BE(sat)} ⁽¹⁾ Base voltag	voltage	I _C =2.5A	I _B =0.5A			1.2	V
h _{FE} DC c	urrent gain	I _C =10mA	V _{CE} =5V	10			
	DC current gain	I _C =2A	V _{CE} =5V	14		28	
Resis	stive load	$V_{CC} = 125V$	I _C =2A				
t _s Stora	ge time	$I_{B1} = -I_{B2} = 0.4$	A	1.5		3	μs
t _f Fall ti	me	$t_p = 30 \mu s$ (s	ee fig.12)		0.2	0.4	μs
Induc	tive load	I _C =2A	I _{B1} =0.4A				
t _s Stora	ge time	$V_{BE(off)} = -5V$	$R_{BB} = 0\Omega$		0.6	1	μs
t _f Fall ti	me	$V_{clamp}=200V$	(see fig.13)		0.1	0.2	μs

 Table 3.
 Electrical characteristics

Note (1) Pulsed duration = 300 $\mu s,$ duty cycle ${\leq}1.5\%$



BUL704

2.1 Electrical characteristics (curves)

Figure 1. Safe operating area F

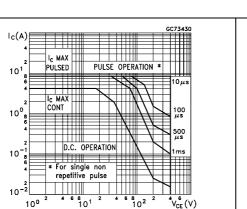


Figure 2. Derating Curve

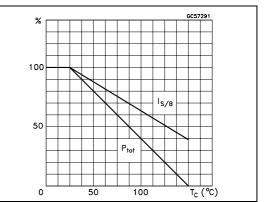


Figure 3. DC current gain

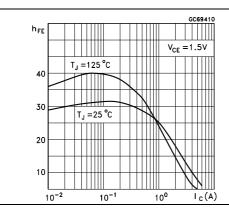


Figure 4. DC current gain

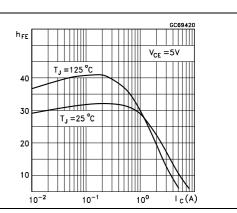
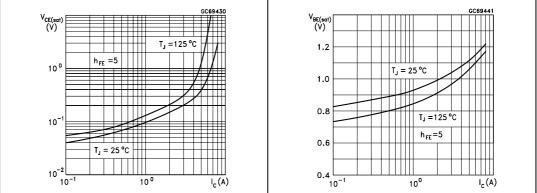


Figure 5. Collector-emitter saturation Figure 6. Base-emitter saturation voltage



GC70840

 $V_{Clamp} = 200 V$

 $V_{BE(off)} = -5V$

h_{FE} =5

 $\mathsf{R}_{\mathsf{B}\mathsf{B}}=\mathsf{O}\,\Omega$

5

4

6 I_C(A)

Figure 7. Inductive load fall time Figure 8. Inductive load storage time

 $t_s(\mu s)$

1

0.1

0 1

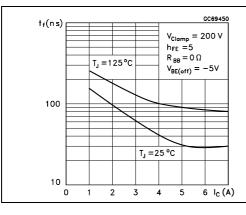
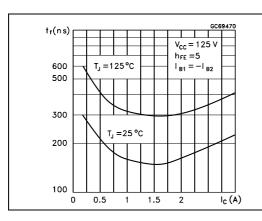


Figure 9. Resistive load fall time



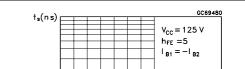


Figure 10. Resistive load storage time

 $T_{J} = 125 \,^{\circ}C$

T_J = 25 °C

2 3

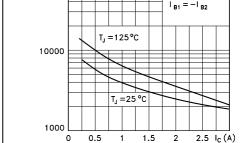
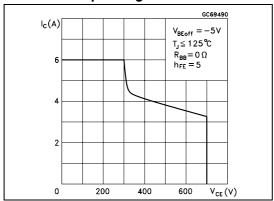


Figure 11. Reverse biased safe operating area





2.2 Test circuits

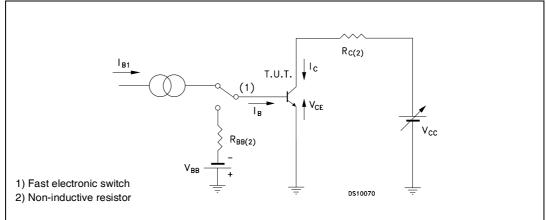
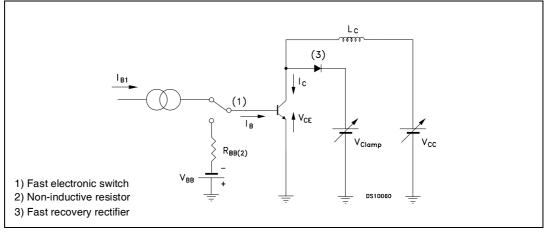


Figure 12. Resistive load switching test circuit







3 Package mechanical data

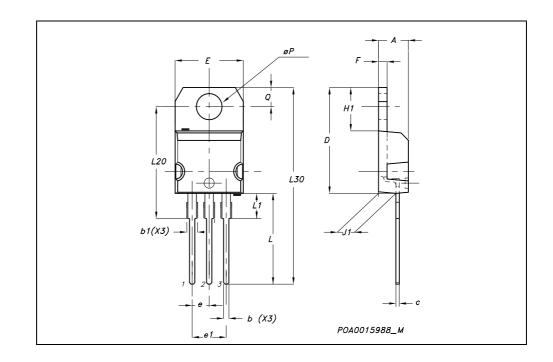
In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

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DIM.		mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А	4.40		4.60	0.173		0.181	
b	0.61		0.88	0.024		0.034	
b1	1.15		1.70	0.045		0.066	
С	0.49		0.70	0.019		0.027	
D	15.25		15.75	0.60		0.620	
Е	10		10.40	0.393		0.409	
е	2.40		2.70	0.094		0.106	
e1	4.95		5.15	0.194		0.202	
F	1.23		1.32	0.048		0.052	
H1	6.20		6.60	0.244		0.256	
J1	2.40		2.72	0.094		0.107	
L	13		14	0.511		0.551	
L1	3.50		3.93	0.137		0.154	
L20		16.40			0.645		
L30		28.90			1.137		
øP	3.75		3.85	0.147		0.151	
Q	2.65		2.95	0.104		0.116	





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4 Revision history

Date	Revision	Changes
30-May-2006	1	Initial release.



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